SPDT SWITCH GaAs MMIC

+2.5~+5.5V

2uA typ

44dB typ. @f=0.1~2GHz

0.6dB typ. @f=1.0GHz 1.0dB typ. @f=2.0Ghz

■GENERAL DESCRIPTION

NJG1512HD3 is a GaAs SPDT switch IC featuring high isolation and low insertion loss.

This switch allows low operating voltage from 2.5V at the wide frequency range from 1MHz to 3GHz.

The ultra small & ultra thin USB6-D3 package is applied.

FEATURES

JRC

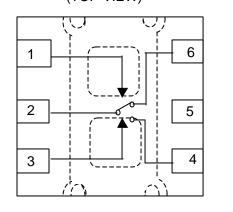
- Single, low voltage control
- High isolation
- Low insertion loss

•Low current consumption

•Ultra small & ultra thin package

■PIN CONFIGURATION

HD3 Type (TOP VIEW)



Pin Connection 1.VCTL2 2.PC 3.VCTL1 4.P1 5.GND 6.P2

USB6-D3 (Package size: 2.0x1.8x0.8mm)

TRUTH TABLE

"H"=V_{СТК (Н),} "L"=V_{СТК (L)}

V _{CTR1}	Н	L
V _{CTR2}	L	Н
PC-P1	OFF	ON
PC-P2	ON	OFF



and low inserti allows low op uency range fro small & ultra

■ABSOLUTE MAXIMUM RATINGS

$(T_a=25^{\circ}C, Z_s=Z_l=50\Omega)$					
PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS	
Input Power	P _{in}	V _{CTL} =0V/2.7V	27	dBm	
Control Voltage	V _{CTR}		6.0	V	
Power Dissipation	PD		200	mW	
Operating Temp.	T _{opr}		-20~+85	°C	
Storage Temp.	T _{stg}		-40~+150	°C	

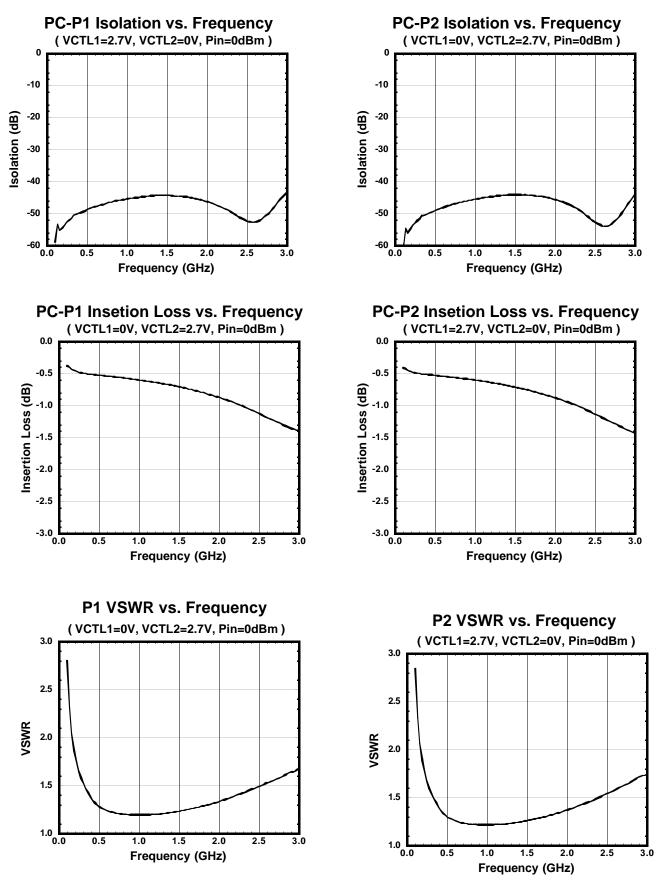
■ELECTRICAL CHARACTERISTICS

(TEST CIRCUIT : $V_{CTL}=0/2.7V$, $Z_s=Z_o=50\Omega$, $T_a=25^{\circ}C$)						
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Control voltage (L)	V _{CTL (L)}		-0.2	0	0.2	V
Control voltage (H)	V _{CTL (H)}		2.5	2.7	5.5	V
Control current	I _{CTL}		-	2.0	4.0	uA
Insertion loss 1	LOSS1	f=1.0GHz, P _{in} =0dBm	-	0.6	1.0	dB
Insertion loss 2	LOSS2	f=2.0GHz, P _{in} =0dBm	-	1.0	1.2	dB
Isolation 1	ISL1	f=1.0GHz, P _{in} =0dBm	41	44	-	dB
Isolation 2	ISL2	f=2.0GHz, P _{in} =0dBm	41	44	-	dB
Pin at 1dB compression point	P _{-1dB}	f=2.0GHz	19.0	22.0	-	dBm
VSWR	VSWR	f=0.1~2.5GHz, ON STATE	-	1.2	1.8	
Switching time	T _{SW}	f=0.1~2.5GHz	-	8	-	ns

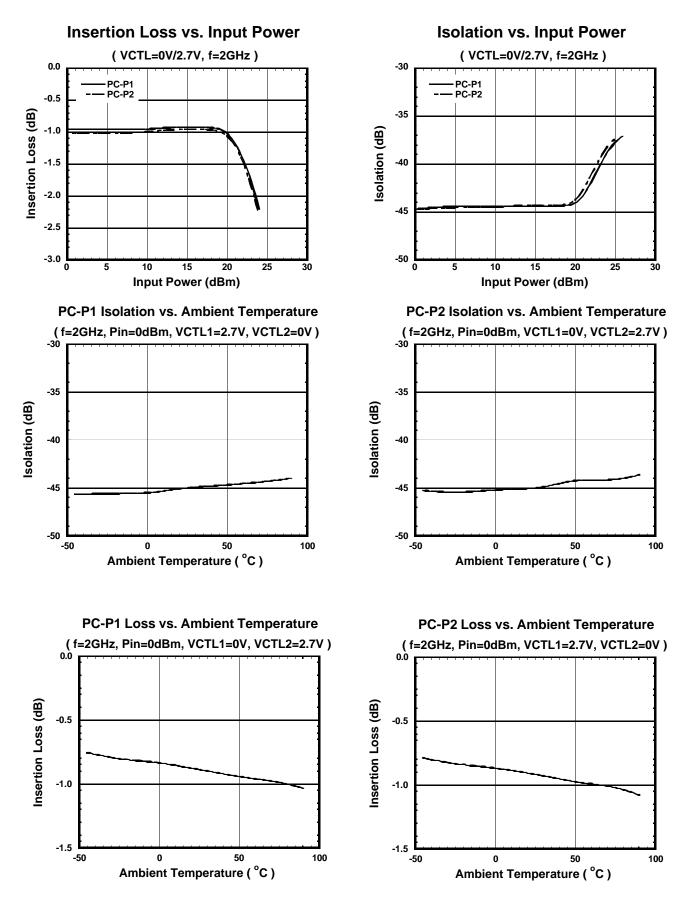
■TERMINAL INFORMATION

No.	SYMBOL	EXPLANATION
1	VCTL1	Control port 1. The voltage of this port controls PC to P1 state. The 'ON' and 'OFF' state is toggled by controlling voltage of this terminal such as high-state (2.5~5.5V) or low-state (-0.2~+0.2V). The voltage of 3rd pin has to be set to opposite state. The bypass capacitor has to be chosen to reduce switching speed delay from 10pF~1000pF range.
2	PC	Common RF port. In order to block the DC bias voltage of internal circuit, an external capacitor is required. (1~500MHz: 1uF, 0.5~2.5GHz: 56pF)
3	VCTL2	Control port 2. The voltage of this port controls PC to P1 state. The 'ON' and 'OFF' state is toggled by controlling voltage of this terminal such as high-state (2.5~5.5V) or low-state (-0.2~+0.2V). The voltage of 1st pin has to be set to opposite state. The bypass capacitor has to be chosen to reduce switching speed delay from 10pF~1000pF range.
4	P1	RF port. This port is connected with PC port by controlling 1st pin ($V_{CTL (H)}$) to 2.5~5.5V and 3rd pin ($V_{CTL (L)}$) to -0.2~+0.2V. An external capacitor is required to block the DC bias voltage of internal circuit. (1~500MHz: 1uF, 0.5~2.5GHz: 56pF)
5	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
6	P2	RF port. This port is connected with PC port by controlling 3rd pin ($V_{CTL (H)}$) to 2.5~5.5V and 1st pin ($V_{CTL (L)}$) to -0.2~+0.2V. An external capacitor is required to block the DC bias voltage of internal circuit. (1~500MHz: 1uF, 0.5~2.5GHz: 56pF)

TYPICAL CHARACTERISTICS

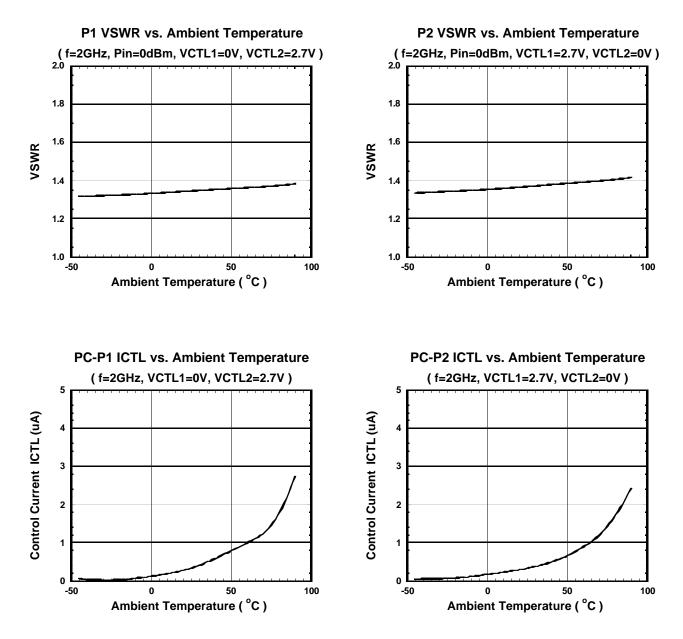


TYPICAL CHARACTERISTICS

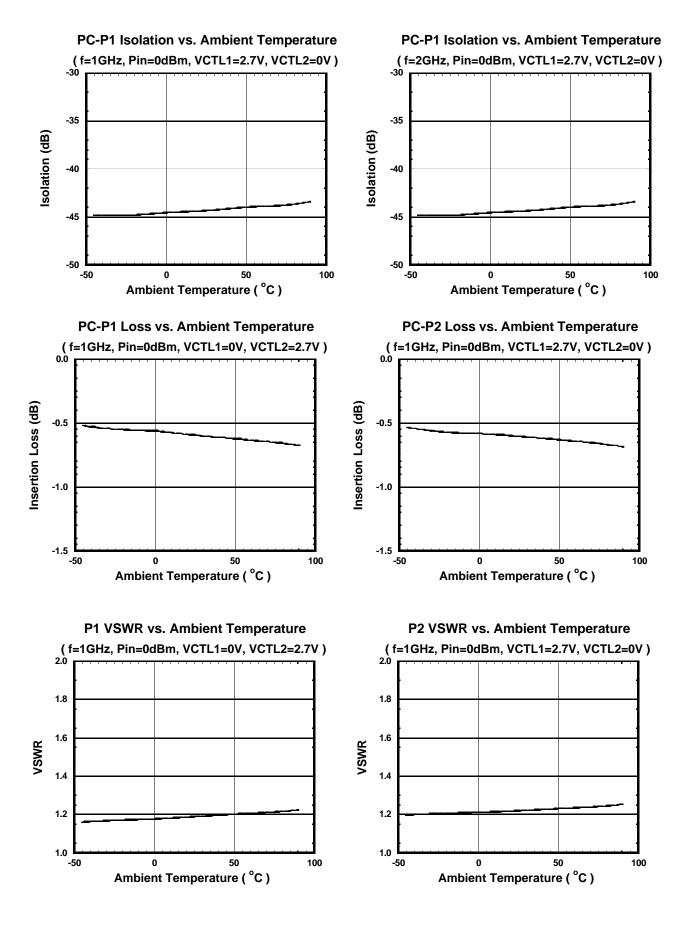


NJG1512HD3

TYPICAL CHARACTERISTICS



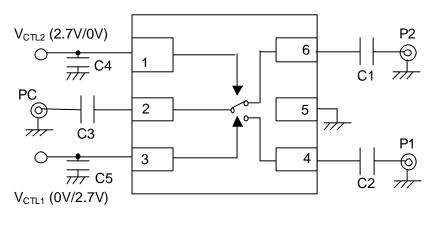
■TYPICAL CHARACTERISTICS



NJG1512HD3

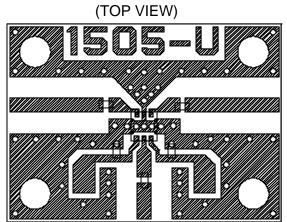
■APPLICATION CIRCUIT: Single control signal operation by using C-MOS inverter

(frequency range: 0.1~2.0GHz)



	Test circuit 1 0.5~2GHz	Test circuit 2 1~500MHz
C1~C3	56pF	0.1uF
C4, C5	10pF	1000pF

■RECOMMENDED PCB DESIGN

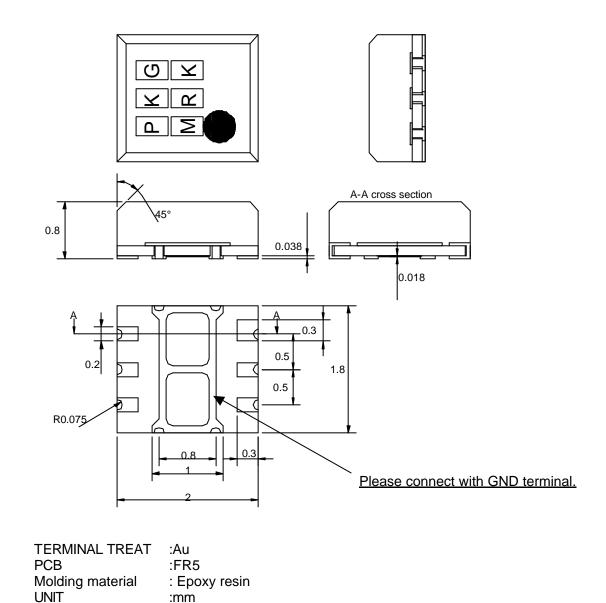


PCB SIZE=19.4x14.0mm PCB: FR-4, t=0.5mm STRIPLINE WIDTH =1mm CAPACITOR: size 1005

PRECAUTIONS

- [1] The external capacitors should be connected to the input and output RF terminals (P_1, P_2, P_C) to block DC current. Please use a 0.1uF capacitor at 1 to 500MHz, a 56pF at 500MHz to 2.0GHz.
- [2] To avoid coupling between terminals, the capacitors have to be placed at the control terminals (V_{CTR1}, V_{CTR2}) as close as possible. The capacitor values of 1000pF at 1 to 500MHz, 10pF at 500MHz to 2GHz are desired. In general, the switching time is depending on the capacitor values, so please be careful choosing capacitor values.
- [3] For good isolation characteristics, the ground terminals (5pin) should be directly connected to the ground patterns and through-holes as close as possible using relatively wide patterns.

■ PACKAGE OUTLINE (USB10-D3)



Cautions	on	using	this	product

WEIGHT

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

:13mg

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights

New Japan Radio Co., Ltd.